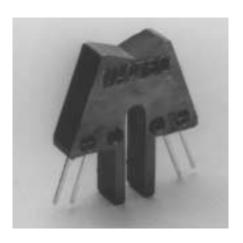
**Arrow Retro with PCB Mount Leads** 



#### PRODUCT DESCRIPTION

This series of reflective optical switches combines an infrared emitting diode (IRED) with an NPN phototransistor (VTR16D1H) in a one piece, sealed, IR transmitting plastic case. The sealed construction improves resistance to moisture and debris. Units have PC board mount leads. Refer to VTR17xxH for devices with flying leads.

# **RoHS Compliant**



### ABSOLUTE MAXIMUM RATINGS

**Maximum Temperatures** 

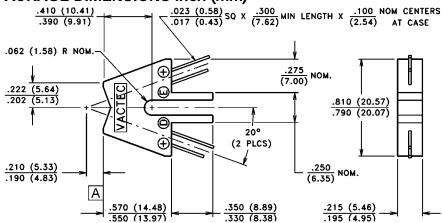
Storage and Operating: -40°C to 85°C

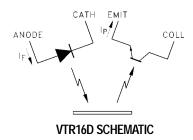
Lead Soldering Temperature: 260°C (1.6 mm from case, 5 seconds max.)

## GENERAL CHARACTERISTICS (@ 25°C unless otherwise noted)

Parameter	Symbol	Text Conditions	Input IRED	Output Detector
Reverse Voltage	V <sub>R</sub>	I <sub>D</sub> - 100 μA	2.0V Min.	·
Continuous Forward Current	l <sub>E</sub>	Derate 0.73 mA/°C above 30°C	40 mA Max.	
Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> = 20 mA	1.8V Max.	
Collector Breakdown Voltage	V <sub>BR(CEO)</sub>	I <sub>C</sub> = 100 μA		30V Min.
Emitter Breakdown Voltage	V <sub>BR(ECO)</sub>	I <sub>E</sub> = 100 μΛ		5.0V Min.
Power Dissination	D <sub>-</sub>	Derate 0.01 mW/°C above 30°C		50 mW May

PACKAGE DIMENSIONS inch (mm)





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SUNSTAR自动化 http://www.sensor-ic.com/ TEL: 0755-83376489 FAX:0755-83376182 E-MAIL: szss20@163.com

## ELEASTRO DE LA ALICHARACTERISTICS (@725° 63/660000 leva course 8/3 pagres 20/122): szss200163.com

		LIGHT CURRENT, Ip (2)				DARK CURRENT (3) (4)		(3) (4)	
	PART NO. (1) (5)	mA Min.	Test Conditions  Le mA Voe Volts		Test Conditions  μΑ Max.		onditions V <sub>CE</sub> Volts	OUTPUT ELEMENT DETECTOR DEVICE	
			i i iii	L VOE VIM.	inches (mm)		<u> </u>	I VOE WITH I	
•	VTR16D1H	0.3	20	5	0.10 (2.5)	0.1	0	5	Phototransistor

Notes:

- 1. The case material is polysulfone and should be cleaned with alcohol or freon TF only. Avoid chlorinated hydrocarbons and solvents such as acetone or toluene, as damage may result.
- 2. The light current is measured using a 90% reflective surface at the specified distance from Ref. A (refer to Package Dimension Outline on previous page).
- 3. The dark current is measured with the part totally shielded from ambient light. With 2150 lux (200 fc) from a cool white fluorescent lamp perpendicular to the sensing axis, the detector current will be typically 3 µA for VTR16D1H. The same illumination concentric to the sensing axis will result in a detector current of 50 µA for VTR16D1H. Equivalent light from an incandescent lamp will result in significantly greater currents.
- 4. With the specified IRED forward current and no reflecting surface, the crosstalk is typically less than 3 μA for VTR16D1H.
- 5. VTR16D1H accommodates most applications.